

LEAD-FREE / RoHS-COMPLIANT HIGH POWER BIAS TEE

BT1-0050

The BT1-0050 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BT1-0050 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BT1-0050 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.



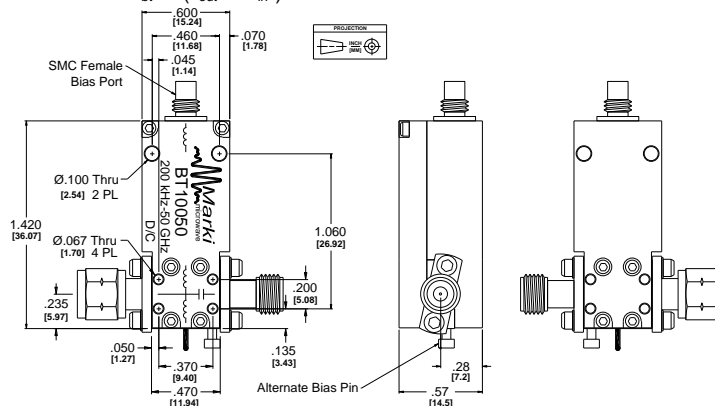
Features

- Broadband: 200 kHz to 50 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

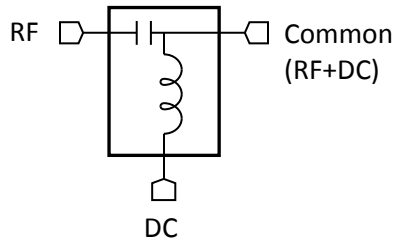
Electrical Specifications - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.

Parameter	Frequency Range	Min	Typ	Max
Insertion Loss (dB)	300 kHz-50 GHz		1.5	2.5
	200-300 kHz		2	
DC Port Isolation (dB)	200 kHz -1 GHz		50	
	1-50 GHz		30	
Return Loss (dB)	200 kHz-50 GHz		13	
RF Power (W)				5
DC Current (A)				1
DC Voltage (V)				50
DC Resistance (Ω)			1	
Inductance (uH)			330	
Capacitance (nF)			100	
Weight (g)			23.5	
Risetime /Falltime (ps) ¹			10	

¹Specified as 90%/10%. Calculated from $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$



Schematic



Application Examples

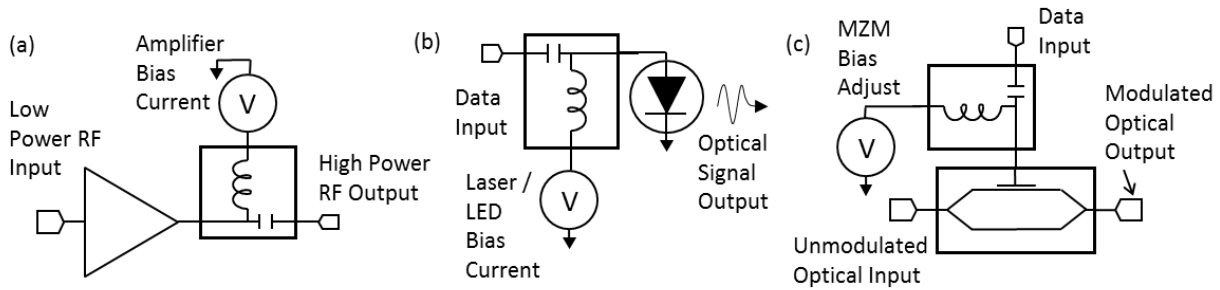


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication

Typical Performance

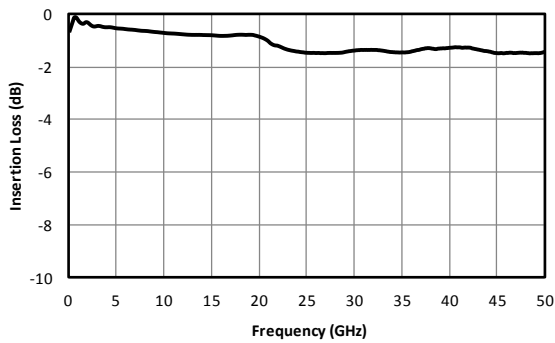


Fig. 2. RF insertion loss.

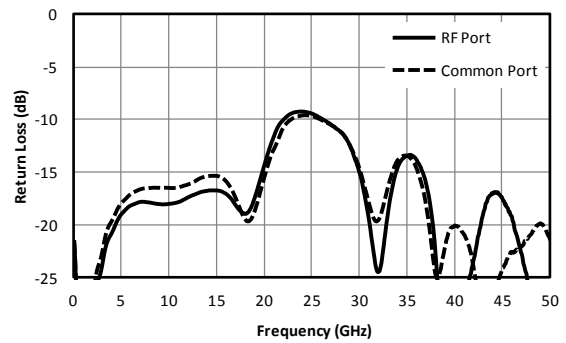


Fig. 3. Return loss.

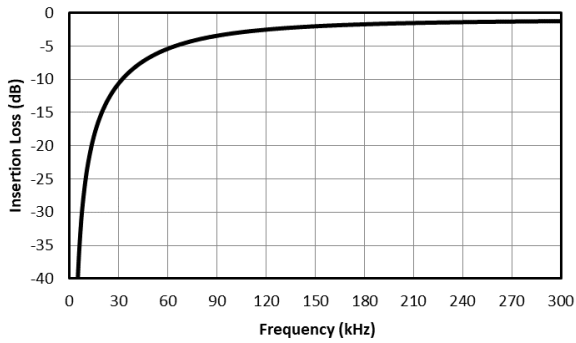


Fig. 4. Low frequency RF response.

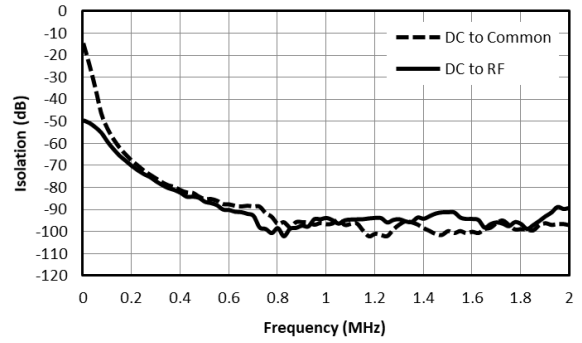


Fig. 5. Low frequency isolation.

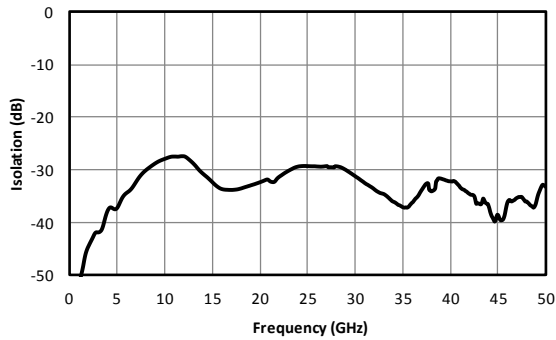


Fig. 6. DC-RF isolation.

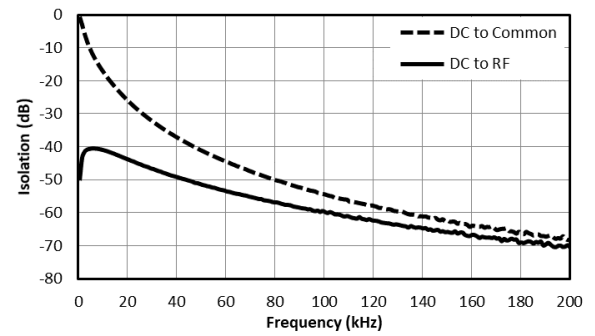


Fig. 7. Near DC isolation

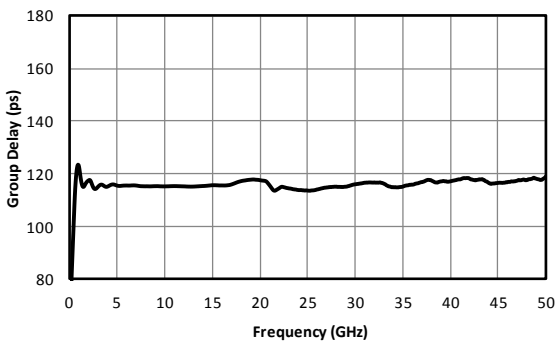


Fig. 8. Group delay.

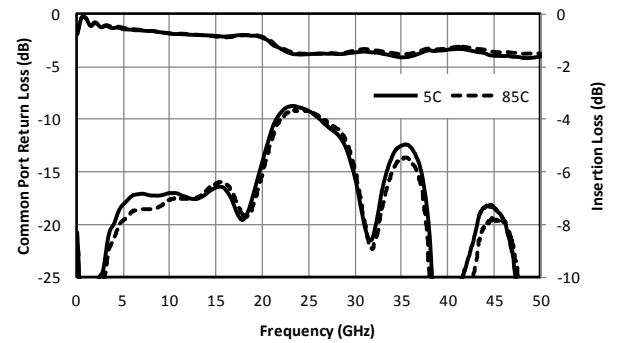


Fig. 9. Performance over temperature

HIGH POWER BIAS TEE

BT1-0050

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Typical Performance vs Bias Current at Low frequencies

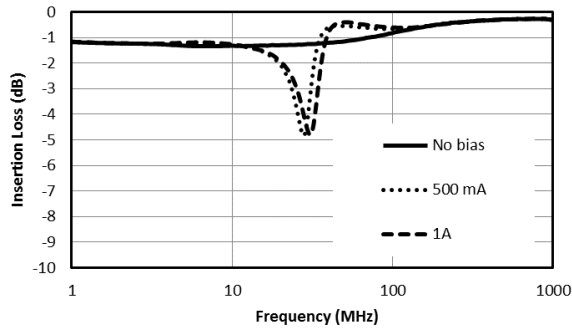


Fig. 10. Insertion Loss vs Bias Current.

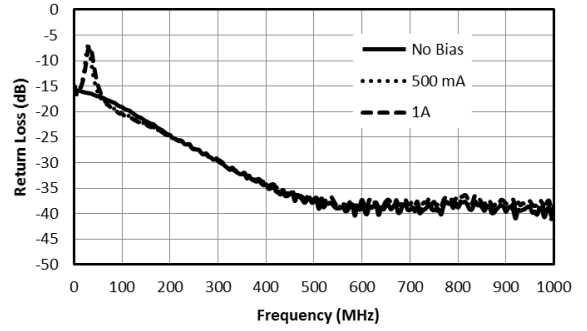


Fig. 11. Common Return Loss vs Bias Current.

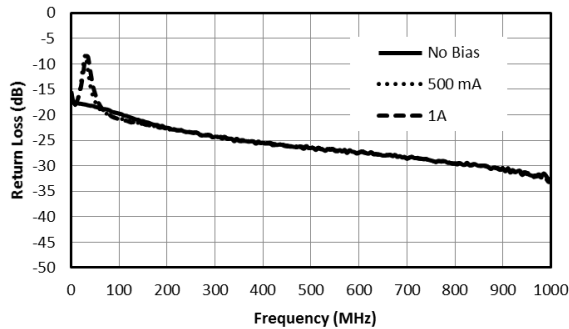


Fig. 12. RF Return Loss vs Bias Current.

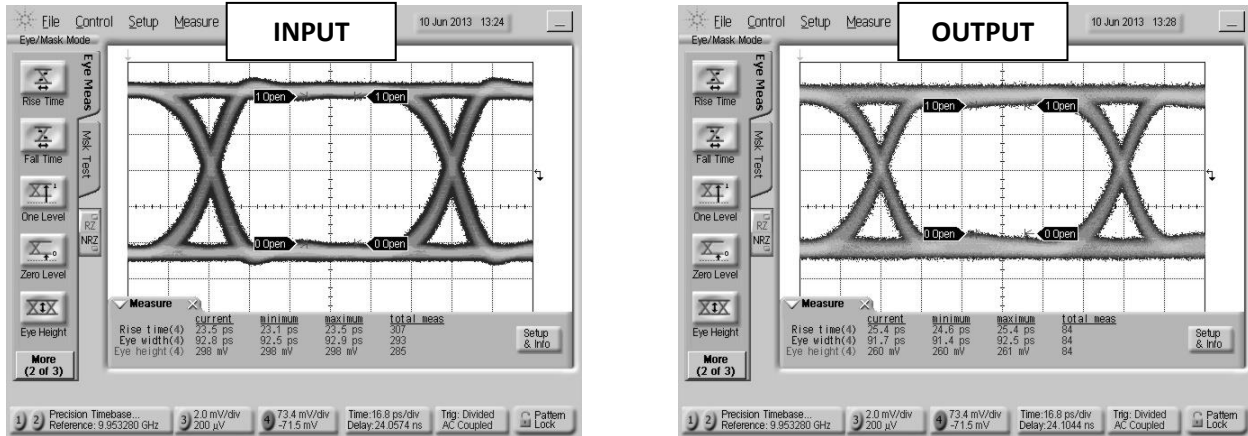


Fig. 13. Oscilloscope measurements of the BT1-0050 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a $2^{31}-1$ PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description
BT1-0050	200 kHz to 50 GHz High Power Bias Tee with 2.4 mm connectors ¹ , LEAD-FREE/RoHS COMPLIANT

¹Consult factory for other connector options.

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Revision History

Revision code	Revision Date	Comment
B	April 2020	Performance vs Bias current plots
C	March 2021	Updated Spec Table and Low Frequency Plots